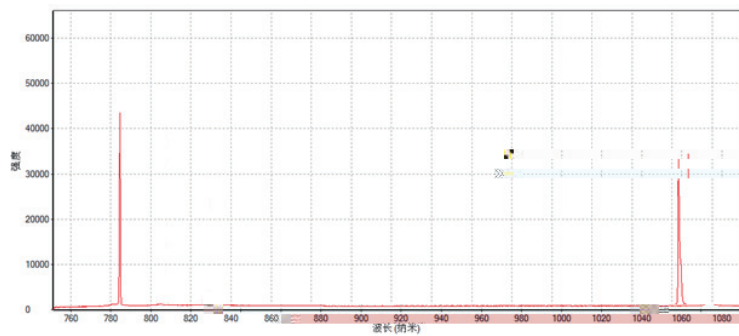


R2T

	P_{op} mW	500/500
	nm	± 0.5
	nm	< 0.1
	/ T nm/	0.01
	I_{th} A	0.4 0.4
	I_{op} A	1.2 1.2
	V_{op} V	2 2
	R_{es}	0.7 0.7
PD	I_{pd} μA	< 2000
	R_t k / 25	$10 \pm 5\% / 3$
TEC	I_{max} A	2.2
TEC	V V	8.7
	dcore μm	105
	Dclad μm	125
	Dbuffer μm	250
	L cm	100 ± 10
	NA	0.22
		FC/PC S/



785&1064nm